Transmissive Sensor

FEATURES

- Choice of phototransistor or photodarlington output
- Side mount package
- · Accurate position sensing
- 0.125 in.(3.18 mm) slot width



INFRA-75.TIF

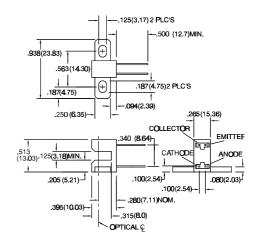
DESCRIPTION

The HOA1884 series consists of an infrared emitting diode facing an NPN silicon phototransistor (HOA1884-011, -012) or photodarlington (HOA1884-013) encased in a black thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The side mounting package is useful in applications in which the interruptive element is parallel to the mounting plane. Both emitter and detector have a 0.020 in.(.508 mm) x 0.040 in.(1.02 mm) vertical aperture. The HOA1884 series employs plastic molded components. For additional component information see SEP8506, SDP8406, and SDP8106.

Housing material is polyester. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

OUTLINE DIMENSIONS in inches (mm)

Tolerance 3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM_054.cdr



Transmissive Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I _F =20 mA
Reverse Leakage Current	I _R			10	μΑ	V _R =3 V
DETECTOR Collector-Emitter Breakdown Voltage HOA1884-011, -012 HOA1884-013	V _(BR) ceo	30 15			V	Ic=100 μA
Emitter-Collector Breakdown Voltage	V _{(BR)ECO}	5.0			V	I _E =100 μA
Collector Dark Current HOA1884-011, -012 HOA1884-013	ICEO			100 250	nA	V _{CE} =10 V I _F =0
COUPLED CHARACTERISTICS On-State Collector Current HOA1884-011 HOA1884-012 HOA1884-013	Ic(on)	0.3 1.8 4.0			mA	V _{CE} =5 V I _F =20 mA
Collector-Emitter Saturation Voltage HOA1884-011 HOA1884-012 HOA1884-013	Vce(sat)			0.4 0.4 1.1	V	I _F =20 mA I _C =40 μA I _C =230 μA I _C =500 μA
Rise And Fall Time HOA1884-011, -012 HOA1884-013	t _r , t _f		15 75		μs	Vcc=5 V, lc=1 mA R_L =1000 Ω R_L =100 Ω

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -40°C to 85°C

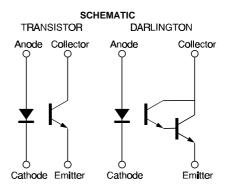
Storage Temperature Range -40°C to 85°C

Soldering Temperature (5 sec) 240°C

IR EMITTER
Power Dissipation 100 mW ⁽¹⁾
Reverse Voltage 3 V

Continuous Forward Current 50 mA

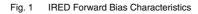
DETECTORTRANS.DARLINGTONCollector-Emitter Voltage30 V15 VEmitter-Collector Voltage5 V5 VPower Dissipation100 mW (¹)100 mW (¹)Collector DC Current30 mA30 mA

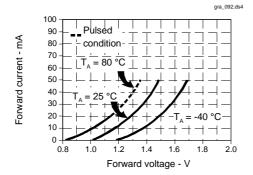


Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

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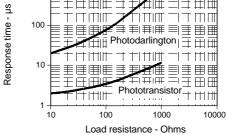
Transmissive Sensor



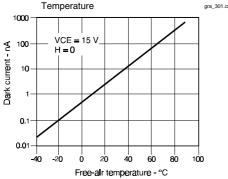


Load Resistance 1000 ▤◾▦▦ 100 Photodarlington = = = =

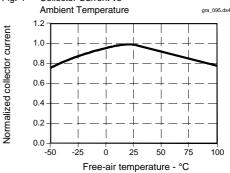
Non-Saturated Switching Time vs



Dark Current vs Fig. 3



Collector Current vs Fig. 4



All Performance Curves Show Typical Values

Transmissive Sensor

X-ON Electronics

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